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Is Now

# Onsemi

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# **CMOS MSI**

# **Quad R-S Latches**

The MC14043B and MC14044B quad R–S latches are constructed with MOS P–Channel and N–Channel enhancement mode devices in a single monolithic structure. Each latch has an independent Q output and set and reset inputs. The Q outputs are gated through three–state buffers having a common enable input. The outputs are enabled with a logical "1" or high on the enable input; a logical "0" or low disconnects the latch from the Q outputs, resulting in an open circuit at the Q outputs.

# Features

- Double Diode Input Protection
- Three-State Outputs with Common Enable
- Outputs Capable of Driving Two Low–power TTL Loads or One Low–Power Schottky TTL Load Over the Rated Temperature Range
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

## MAXIMUM RATINGS (Voltages Referenced to V<sub>SS</sub>)

| Symbol                             | Parameter  | Value                         | Unit |
|------------------------------------|--|-------------------------------|------|
| V <sub>DD</sub>                    | DC Supply Voltage Range                              | -0.5 to +18.0                 | V    |
| V <sub>in</sub> , V <sub>out</sub> | Input or Output Voltage Range<br>(DC or Transient)   | –0.5 to V <sub>DD</sub> + 0.5 | V    |
| I <sub>in</sub> , I <sub>out</sub> | Input or Output Current<br>(DC or Transient) per Pin | ±10                           | mA   |
| P <sub>D</sub>                     | Power Dissipation, per Package<br>(Note 1)           | 500                           | mW   |
| T <sub>A</sub>                     | Ambient Temperature Range                            | -55 to +125                   | °C   |
| T <sub>stg</sub>                   | Storage Temperature Range                            | -65 to +150                   | °C   |
| TL                                 | Lead Temperature<br>(8–Second Soldering)             | 260                           | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Packages: -7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$ 

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.



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D SUFFIX CASE 751B SOEIAJ-16 F SUFFIX CASE 966

#### MARKING DIAGRAMS



## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# **PIN ASSIGNMENT**

| м | C1 | 40 | 43B |  |
|---|----|----|-----|--|

|                   |    |    | _                 |
|-------------------|----|----|-------------------|
| Q3 [              | 1● | 16 | ] V <sub>DD</sub> |
| Q0 [              | 2  | 15 | ] R3              |
| R0 [              | 3  | 14 | ] S3              |
| S0 [              | 4  | 13 | ] NC              |
| E                 | 5  | 12 | ] S2              |
| S1 [              | 6  | 11 | ] R2              |
| R1 [              | 7  | 10 | ] Q2              |
| v <sub>ss</sub> [ | 8  | 9  | ] Q1              |
|                   |    |    |                   |

| MC14044B          |    |    |                   |  |  |  |
|-------------------|----|----|-------------------|--|--|--|
| Q3 [              | 1● | 16 | D V <sub>DD</sub> |  |  |  |
| NC [              | 2  | 15 | ] <u>53</u>       |  |  |  |
| S0 [              | 3  | 14 | ] R3              |  |  |  |
| R0 [              | 4  | 13 | ] Q0              |  |  |  |
| E                 | 5  | 12 | ] R2              |  |  |  |
| R1 [              | 6  | 11 | ] <u>52</u>       |  |  |  |
| <u>S1</u> [       | 7  | 10 | ] Q2              |  |  |  |
| v <sub>ss</sub> [ | 8  | 9  | ] Q1              |  |  |  |

NC = NO CONNECTION





**TRUTH TABLE** 

| S   | R              | Е | Q                 |  |  |  |
|-----|----------------|---|-------------------|--|--|--|
| Х   | X              | 0 | High<br>Impedance |  |  |  |
| 0   | 0              | 1 | 0                 |  |  |  |
| 0   | 1              | 1 | 1                 |  |  |  |
| 1   | 0              | 1 | 0                 |  |  |  |
| 1   | 1              | 1 | No Change         |  |  |  |
| X = | X = Don't Care |   |                   |  |  |  |

| ELECTRICAL CHARA | CTERISTICS | (Voltages Re | eferenced to | V <sub>SS</sub> ) |
|------------------|------------|--------------|--------------|-------------------|
|------------------|------------|--------------|--------------|-------------------|

|   |           |                 |                        | - 5   | 5°C                  | 25°C                          |                                | 125°C                |                               |                      |      |
|---|-----------|-----------------|------------------------|---|----------------------|-------------------------------|--------------------------------|----------------------|-------------------------------|----------------------|------|
| Characteristic  |           | Symbol          | V <sub>DD</sub><br>Vdc | Min   | Max                  | Min                           | Typ<br>(Note 2)                | Max                  | Min                           | Max                  | Unit |
| Output Voltage<br>V <sub>in</sub> = V <sub>DD</sub> or 0  | "0" Level | V <sub>OL</sub> | 5.0<br>10<br>15        | -<br>-<br>-   | 0.05<br>0.05<br>0.05 | -<br>-<br>-                   | 0<br>0<br>0                    | 0.05<br>0.05<br>0.05 | -<br>-<br>-                   | 0.05<br>0.05<br>0.05 | Vdc  |
| $V_{in} = 0 \text{ or } V_{DD}$   | "1" Level | V <sub>OH</sub> | 5.0<br>10<br>15        | 4.95<br>9.95<br>14.95   | -<br>-<br>-          | 4.95<br>9.95<br>14.95         | 5.0<br>10<br>15                |                      | 4.95<br>9.95<br>14.95         | -<br>-<br>-          | Vdc  |
| Input Voltage<br>$(V_O = 4.5 \text{ or } 0.5 \text{ Vdc})$<br>$(V_O = 9.0 \text{ or } 1.0 \text{ Vdc})$<br>$(V_O = 13.5 \text{ or } 1.5 \text{ Vdc})$       | "0" Level | VIL             | 5.0<br>10<br>15        | _<br>_<br>_   | 1.5<br>3.0<br>4.0    | _<br>_<br>_                   | 2.25<br>4.50<br>6.75           | 1.5<br>3.0<br>4.0    | _<br>_<br>_                   | 1.5<br>3.0<br>4.0    | Vdc  |
| $(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$<br>$(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$<br>$(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$                        | "1" Level | V <sub>IH</sub> | 5.0<br>10<br>15        | 3.5<br>7.0<br>11  | -<br>-<br>-          | 3.5<br>7.0<br>11              | 2.75<br>5.50<br>8.25           |                      | 3.5<br>7.0<br>11              | _<br>_<br>_          | Vdc  |
| $\begin{array}{l} \mbox{Output Drive Current} \\ (V_{OH} = 2.5 \ Vdc) \\ (V_{OH} = 4.6 \ Vdc) \\ (V_{OH} = 9.5 \ Vdc) \\ (V_{OH} = 13.5 \ Vdc) \end{array}$ | Source    | I <sub>ОН</sub> | 5.0<br>5.0<br>10<br>15 | -3.0<br>-0.64<br>-1.6<br>-4.2   | -<br>-<br>-          | -2.4<br>-0.51<br>-1.3<br>-3.4 | -4.2<br>-0.88<br>-2.25<br>-8.8 | -<br>-<br>-          | -1.7<br>-0.36<br>-0.9<br>-2.4 | -<br>-<br>-<br>-     | mAdc |
| $(V_{OL} = 0.4 \text{ Vdc})$<br>$(V_{OL} = 0.5 \text{ Vdc})$<br>$(V_{OL} = 1.5 \text{ Vdc})$  | Sink      | I <sub>OL</sub> | 5.0<br>10<br>15        | 0.64<br>1.6<br>4.2  | -<br>-<br>-          | 0.51<br>1.3<br>3.4            | 0.88<br>2.25<br>8.8            | -<br>-<br>-          | 0.36<br>0.9<br>2.4            | -<br>-<br>-          | mAdc |
| Input Current   |           | l <sub>in</sub> | 15                     | -   | ±0.1                 | -                             | ±0.00001                       | ±0.1                 | -                             | ±1.0                 | μAdc |
| Input Capacitance<br>(V <sub>in</sub> = 0)  |           | C <sub>in</sub> | -                      | -   | -                    | -                             | 5.0                            | 7.5                  | -                             | -                    | pF   |
| Quiescent Current<br>(Per Package)  |           | I <sub>DD</sub> | 5.0<br>10<br>15        | -<br>-<br>-   | 1.0<br>2.0<br>4.0    |                               | 0.002<br>0.004<br>0.006        | 1.0<br>2.0<br>4.0    | _<br>_<br>_                   | 30<br>60<br>120      | μAdc |
| Total Supply Current (Notes 3 & 4)<br>(Dynamic plus Quiescent,<br>Per Package)<br>(C <sub>L</sub> = 50 pF on all outputs all<br>buffers switching)          |           | ΙŢ              | 5.0<br>10<br>15        | $I_{T} = (0.58 \ \mu A/kHz) \ f + I_{DD}$<br>$I_{T} = (1.15 \ \mu A/kHz) \ f + I_{DD}$<br>$I_{T} = (1.73 \ \mu A/kHz) \ f + I_{DD}$ |                      |                               | μAdc                           |                      |                               |                      |      |
| Three–State Output Leaka<br>Current   | ige       | I <sub>TL</sub> | 15                     | -   | ±0.1                 | -                             | ±0.0001                        | ±0.1                 | -                             | ±3.0                 | μAdc |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
 The formulas given are for the typical characteristics only at 25°C.
 To calculate total supply current at loads other than 50 pF:

 $I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$ 

where:  $I_T$  is in  $\mu A$  (per package),  $C_L$  in pF, V = (V\_{DD} - V\_{SS}) in volts, f in kHz is input frequency, and k = 0.004.

## SWITCHING CHARACTERISTICS (Note 5) ( $C_L = 50 \text{ pF}, T_A = 25^{\circ}C$ )

| Characteristic  | Symbol   | V <sub>DD</sub><br>Vdc | Min              | Typ<br>(Note 6) | Max               | Unit |
|---|--|------------------------|------------------|-----------------|-------------------|------|
| Output Rise Time<br>$t_{TLH} = (1.35 \text{ ns/pF}) C_L + 32.5 \text{ ns}$<br>$t_{TLH} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$<br>$t_{TLH} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$  | t <sub>TLH</sub>   | 5.0<br>10<br>15        | -<br>-<br>-      | 100<br>50<br>40 | 200<br>100<br>80  | ns   |
| Output Fall Time<br>$t_{THL} = (1.35 \text{ ns/pF}) C_L + 32.5 \text{ ns}$<br>$t_{THL} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$<br>$t_{THL} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$  | t <sub>THL</sub>   | 5.0<br>10<br>15        | -<br>-<br>-      | 100<br>50<br>40 | 200<br>100<br>80  | ns   |
| $\begin{array}{l} \mbox{Propagation Delay Time} \\ t_{PLH} = (0.90 \mbox{ ns/pF}) \mbox{ C}_{L} + 130 \mbox{ ns} \\ t_{PLH} = (0.36 \mbox{ ns/pF}) \mbox{ C}_{L} + 57 \mbox{ ns} \\ t_{PLH} = (0.26 \mbox{ ns/pF}) \mbox{ C}_{L} + 47 \mbox{ ns} \end{array}$ | t <sub>PLH</sub>   | 5.0<br>10<br>15        | -<br>-<br>-      | 175<br>75<br>60 | 350<br>175<br>120 | ns   |
| t <sub>PHL</sub> = (0.90 ns/pF) C <sub>L</sub> + 130 ns<br>t <sub>PHL</sub> = (0.90 ns/pF) C <sub>L</sub> + 57 ns<br>t <sub>PHL</sub> = (0.26 ns/pF) C <sub>L</sub> + 47 ns   | <sup>t</sup> PHL   | 5.0<br>10<br>15        | _<br>_<br>_      | 175<br>75<br>60 | 350<br>175<br>120 | ns   |
| Set, Set Pulse Width  | t <sub>W</sub>   | 5.0<br>10<br>15        | 200<br>100<br>70 | 80<br>40<br>30  | -<br>-<br>-       | ns   |
| Reset, Reset Pulse Width  | t <sub>W</sub>   | 5.0<br>10<br>15        | 200<br>100<br>70 | 80<br>40<br>30  | -<br>-<br>-       | ns   |
| Three–State Enable/Disable Delay  | t <sub>PLZ</sub> ,<br>t <sub>PHZ</sub> ,<br>t <sub>PZL</sub> ,<br>t <sub>PZH</sub> | 5.0<br>10<br>15        | -<br>-<br>-      | 150<br>80<br>55 | 300<br>160<br>110 | ns   |

The formulas given are for the typical characteristics only at 25°C.
 Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



## AC WAVEFORMS

## THREE-STATE ENABLE/DISABLE DELAYS

Set, Reset, Enable, and Switch Conditions for 3-State Tests

|                  |        |        |        |   | MC14043B        |                 | MC14            | 044B            |
|------------------|--------|--------|--------|---|-----------------|-----------------|-----------------|-----------------|
| Test             | Enable | S1     | S2     | Q | S               | R               | S               | R               |
| t <sub>PZH</sub> | ~      | Open   | Closed | А | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>DD</sub> |
| t <sub>PZL</sub> |        | Closed | Open   | В | V <sub>SS</sub> | $V_{DD}$        | V <sub>DD</sub> | V <sub>SS</sub> |
| t <sub>PHZ</sub> | ~      | Open   | Closed | А | $V_{DD}$        | $V_{SS}$        | $V_{SS}$        | $V_{DD}$        |
| t <sub>PLZ</sub> | ~      | Closed | Open   | В | $V_{SS}$        | $V_{DD}$        | $V_{DD}$        | $V_{SS}$        |





#### **ORDERING INFORMATION**

| Device         | Package                | Shipping <sup>†</sup>    |
|----------------|------------------------|--------------------------|
| MC14043BDG     | SOIC-16<br>(Pb-Free)   | 48 Units / Rail          |
| NLV14043BDG*   | SOIC-16<br>(Pb-Free)   | 48 Units / Rail          |
| MC14043BDR2G   | SOIC-16<br>(Pb-Free)   | 2500 Units / Tape & Reel |
| NLV14043BDR2G* | SOIC-16<br>(Pb-Free)   | 2500 Units / Tape & Reel |
| MC14043BFELG   | SOEIAJ-16<br>(Pb-Free) | 2000 Units / Tape & Reel |

| MC14044BDG     | SOIC-16<br>(Pb-Free) | 48 Units / Rail          |
|----------------|----------------------|--------------------------|
| NLV14044BDG*   | SOIC-16<br>(Pb-Free) | 48 Units / Rail          |
| MC14044BDR2G   | SOIC-16<br>(Pb-Free) | 2500 Units / Tape & Reel |
| NLV14044BDR2G* | SOIC-16<br>(Pb-Free) | 2500 Units / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

# PACKAGE DIMENSIONS

SOIC-16 **D SUFFIX** CASE 751B-05 ISSUE K



NOTES:

- NOTES:
  DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

|     | MILLIN | IETERS | INC       | HES   |
|-----|--------|--------|-----------|-------|
| DIM | MIN    | MAX    | MIN       | MAX   |
| Α   | 9.80   | 10.00  | 0.386     | 0.393 |
| В   | 3.80   | 4.00   | 0.150     | 0.157 |
| С   | 1.35   | 1.75   | 0.054     | 0.068 |
| D   | 0.35   | 0.49   | 0.014     | 0.019 |
| F   | 0.40   | 1.25   | 0.016     | 0.049 |
| G   | 1.27   | BSC    | 0.050 BSC |       |
| J   | 0.19   | 0.25   | 0.008     | 0.009 |
| K   | 0.10   | 0.25   | 0.004     | 0.009 |
| M   | 0 °    | 7°     | 0 °       | 7°    |
| Р   | 5.80   | 6.20   | 0.229     | 0.244 |
| R   | 0.25   | 0.50   | 0.010     | 0.019 |

**SOLDERING FOOTPRINT\*** 



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

SOEIAJ-16 **F SUFFIX CASE 966 ISSUE A** 



0.10 (0.004)

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NOTES:

- . DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
- CONTROLLING DIMENSION: MILLIMETER. 2
- B. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE 3. MEASURED AT THE PARTING LINE. MOLD FLASH **OR PROTRUSIONS SHALL NOT EXCEED 0.15** (0.006) PER SIDE.
- (U.U.0) PER SIDE. 4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 ( 0.018).

|                | MILLIMETERS |       | INCHES    |       |
|----------------|-------------|-------|-----------|-------|
| DIM            | MIN         | MAX   | MIN       | MAX   |
| Α              |             | 2.05  |           | 0.081 |
| A <sub>1</sub> | 0.05        | 0.20  | 0.002     | 0.008 |
| b              | 0.35        | 0.50  | 0.014     | 0.020 |
| C              | 0.10        | 0.20  | 0.007     | 0.011 |
| D              | 9.90        | 10.50 | 0.390     | 0.413 |
| E              | 5.10        | 5.45  | 0.201     | 0.215 |
| е              | 1.27 BSC    |       | 0.050 BSC |       |
| HE             | 7.40        | 8.20  | 0.291     | 0.323 |
| L              | 0.50        | 0.85  | 0.020     | 0.033 |
| LE             | 1.10        | 1.50  | 0.043     | 0.059 |
| M              | 0 °         | 10 °  | 0 °       | 10 °  |
| Q <sub>1</sub> | 0.70        | 0.90  | 0.028     | 0.035 |
| Z              |             | 0.78  |           | 0.031 |

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